

L Number	Hits	Search Text	DB	Time stamp
1	47	"cobalt monosilicide"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/14 10:40
2	18	"cobalt monosilicide" and (ratio stoichiometric\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/14 10:40
-	1229	((soi box (silicon adj on adj insulator) (buried adj oxide)) with (fet (field adj effect adj transistor)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/14 10:40
-	1079	((soi box (silicon adj on adj insulator) (buried adj oxide)) with (fet (field adj effect adj transistor))) and @ad<=20010425	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 13:42
-	900	((soi box (silicon adj on adj insulator) (buried adj oxide)) with (fet (field adj effect adj transistor))) and @ad<=20000406	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 13:42
-	311	((((soi box (silicon adj on adj insulator) (buried adj oxide)) with (fet (field adj effect adj transistor))) and @ad<=20000406) and (silicide cobalt co titanium ti))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 13:45
-	90939	((((soi box (silicon adj on adj insulator) (buried adj oxide)) with (fet (field adj effect adj transistor))) and @ad<=20000406) and (silicide cobalt co titanium ti) implant	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 13:43
-	12	((((soi box (silicon adj on adj insulator) (buried adj oxide)) with (fet (field adj effect adj transistor))) and @ad<=20000406) and (silicide cobalt co titanium ti) with implant	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 13:43
-	254	((((soi box (silicon adj on adj insulator) (buried adj oxide)) with (fet (field adj effect adj transistor))) and @ad<=20000406) and (silicide cobalt co titanium ti) and source and drain	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 13:54
-	14	((((soi box (silicon adj on adj insulator) (buried adj oxide)) with (fet (field adj effect adj transistor))) and @ad<=20000406) and (silicide cobalt co titanium ti) and source and drain) and ratio with silicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 13:55
-	3	("5801084" "6096582" "6159824").PN.	USPAT	2002/12/11 13:58
-	6	oki.as. and (soi with fet)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 13:59
-	2	("6190977" "6287901").PN.	USPAT	2002/12/11 14:01
-	1794	soi and fet	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 14:18

	161	(soi and fet) and ((source drain) with silicide)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 14:19
	102	((soi and fet) and ((source drain) with silicide)) and @ad<=20000406	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 14:24
	2	(((soi and fet) and ((source drain) with silicide)) and @ad<=20000406) and silicide with ratio	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 14:27
	2	(((soi and fet) and ((source drain) with silicide)) and @ad<=20000406) and (refractory metal) with (rich stuffed)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 14:28
	2	(((soi box (silicon adj on adj insulator) (buried adj oxide)) with (fet (field adj effect adj transistor))) and @ad<=20000406) and (refractory metal) with (rich stuffed)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 14:28
	7899	(refractory metal) with (rich stuffed)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 14:28
	653	((refractory metal) with (rich stuffed)) and ((438/\$) (257/\$).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 14:30
	71	(((refractory metal) with (rich stuffed)) and ((438/\$) (257/\$).ccls.) and fet	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 14:30
	19	(((refractory metal) with (rich stuffed)) and ((438/\$) (257/\$).ccls.) and fet) and soi	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 14:38
	8	("5288948" or ("6037588") or ("6197601") or ("6274470")).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 15:06
	1	6274470.URPN.	USPAT	2002/12/11 14:40
	2	(drain source) with silicide and stuff\$3 with (refractory metal)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 14:42
	899	(drain source) with silicide and fet	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 14:43
	161	((drain source) with silicide and fet) and soi	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 14:43

	102	((drain source) with silicide and fet) and soi) and @ad<=20000406	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 14:43
	7	5719083.URPN.	USPAT	2002/12/11 14:45
	7	5719083.URPN.	USPAT	2002/12/11 14:45
	10	("3830657" "5084413" "5087296" "5094697" "5112773" "5177569" "5198389" "5254481" "5445982" "5554566").PN.	USPAT	2002/12/11 14:45
	1	6274470.URPN.	USPAT	2002/12/11 14:54
	5	("5869396" "6022457" "6025267" "6083817" "6274470").PN.	USPAT	2002/12/11 14:54
	2	6022457.URPN.	USPAT	2002/12/11 14:59
	14	("4378628" "4814294" "5045496" "5047367" "5356837" "5449642" "5536684" "5567651" "5736461" "5874342" "5902129" "5904564" "5989988" "6022457").PN.	USPAT	2002/12/11 15:00
	14	((cobalt with rich) with silicide) and ((438/\$) (257\$/)).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/11 15:09
	64	4378628.URPN.	USPAT	2002/12/11 15:14
	4331	((438/476) or (438/655) or (438/656) or (438/664) or (438/683) or (438/685)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/13 07:25
	521	((438/476) or (438/655) or (438/656) or (438/664) or (438/683) or (438/685)).CCLS.) and (cobalt)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/13 07:26
	249	((438/476) or (438/655) or (438/656) or (438/664) or (438/683) or (438/685)).CCLS.) and (cobalt)) and (source drain) and electrode	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/13 07:26
	199	((438/476) or (438/655) or (438/656) or (438/664) or (438/683) or (438/685)).CCLS.) and (cobalt)) and (source drain) and electrode) and @ad<=20000406	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/13 07:39
	0	((438/476) or (438/655) or (438/656) or (438/664) or (438/683) or (438/685)).CCLS.) and (cobalt)) and (source drain) and electrode) and @ad<=20000406) and "co.sub.2si"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/13 07:39
	1	((438/476) or (438/655) or (438/656) or (438/664) or (438/683) or (438/685)).CCLS.) and (cobalt)) and (source drain) and electrode) and @ad<=20000406) and cobalt with rich	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/13 07:40
	2	((438/476) or (438/655) or (438/656) or (438/664) or (438/683) or (438/685)).CCLS.) and (cobalt)) and (source drain) and electrode) and @ad<=20000406) and cobalt with excess	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/13 07:41
	71	((438/476) or (438/655) or (438/656) or (438/664) or (438/683) or (438/685)).CCLS.) and (cobalt)) and (source drain) and electrode) and @ad<=20000406) and silicide with low with resistance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/13 08:24

-	1	(((((438/476) or (438/655) or (438/656) or (438/664) or (438/683) or (438/685)).CCLS.) and (cobalt)) and (source drain) and electrode) and @ad<=20000406) and silicide with low with resistance) and (dicobalt (di adj cobalt))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/13 08:24
-	118	(((((438/476) or (438/655) or (438/656) or (438/664) or (438/683) or (438/685)).CCLS.) and (cobalt)) and (source drain) and electrode) and @ad<=20000406) and low with resistance	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/13 13:59
-	12	"cobalt monosilicide" and stable	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/13 14:02
-	3	"cobalt monosilicide" and unstable	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/13 14:02
-	47	"cobalt monosilicide"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/12/13 14:08